

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1517	semiconductor and porous and (low adj k) and (dielectric or insulat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/23 09:37
L2	1280	1 and (open\$3 or trench\$2 or hole or groove)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/23 09:38
L3	1081	2 and (dielectric adj constant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/23 09:38
L4	507	3 and wir\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/23 09:38
L5	97	4 and ((fluorin\$4 and polyarylene) or (carbon adj fluoride) or cf)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/23 09:40